

Thyristor Module

V_{RRM} / **V**_{DRM} 800 to 1600V

 Itav
 200 Amp

 Itrms
 314 Amp

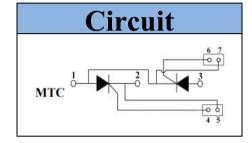
Features

- Aluminum oxide DBC
- · Glass passivated chip
- Thyristor for line frequency
- Long-term stability

Applications

- Power converters
- Lighting control
- DC motor control and drives
- · Heat and temperature control





Module Type

| Туре | V _{RRM} / V _{DRM} | V_{RSM} |
|------------|-------------------------------------|-----------|
| MTC200G-08 | 800V | 900V |
| MTC200G-12 | 1200V | 1300V |
| MTC200G-16 | 1600V | 1700V |

Maximum Ratings

| Symbol | Item | Conditions | Values | Unit |
|-------------------|---|--|--------------|------------------|
| I _{TAV} | Average On-state Current | 180° Conduction Sin Half Wave, T _c = 82°C | 200 | А |
| I _{TRMS} | RMS On-state Current | | 314 | Α |
| I _{TSM} | Surge On-state Current | $T_j = 25^{\circ}C$, $t = 50Hz(10ms)$, $V_R = 0V$ | 6300 | Α |
| I ² t | Circuit Fusing Consideration | t = 10ms T _j =25°C | 198450 | A ² s |
| Viso | Isolation Breakdown Voltage | AC 50Hz/60Hz; R.M.S; 1min | 3000 | V |
| Tj | Operating Junction Temperature | | -40 to + 125 | °C |
| T _{stg} | Storage Temperature | | -40 to + 125 | °C |
| Mt | Mounting Torque | To Terminals(M6) | 5±15% | |
| Ms | Mounting Torque | To Heatsink(M6) | 5±15% | N⋅m |
| Weight | Module (Approximately) | | 180 | g |
| di/dt | Critical Rate of Rise of On-state Current, Max | T_{j} = 125°C, V_{D} = 1/2 V_{DRM} , I_{G} = 150mA, di_{G}/dt = 0.1A/ μ s | 150 | A/μs |

■ Thermal Characteristics

| Symbol | Item | Conditions | Values | Unit |
|----------------------|------------------------|---------------------------------|--------|------|
| R _{th(j-c)} | Thermal Impedance, Max | Junction to Case(Per Thyristor) | 0.13 | °C/W |
| R _{th(c-s)} | Thermal Impedance, Max | Case to Heat Sink | 0.05 | °C/W |



■ Electrical Characteristics

| Symbol | Item | Conditions | Values | | | Unit |
|---------------------------------------|--|--|--------|------|------|------|
| | | | Min. | Тур. | Max. | Jint |
| V _{TM} | Peak On-State Voltage, Max | $T_j = 25^{\circ}C$, $I_T = 600A$ | - | - | 1.60 | V |
| I _{DRM} /I _{RRM} | Repetitive Peak Reverse Current, Max /Repetitive Peak Off-state Current, Max | $T_j = 125$ °C, $V_R = V_{RRM}$, $V_D = V_{DRM}$ | - | - | 35 | mA |
| V_{GT} | Gate Trigger Voltage, Max | $T_j = 25$ °C, $V_D = 6V$ | - | - | 3.0 | V |
| I _{GT} | Gate Trigger Current, Max | $T_j = 25^{\circ}C, V_D = 6V$ | - | - | 150 | mA |
| V_{GD} | Gate Non-Trigger Voltage, Max | $T_j = 125$ °C, $V_D = 2/3V_{DRM}$ | - | - | 0.25 | V |
| IL | Latching Current | T _j = 25°C | - | 200 | - | mA |
| IH | Holding Current | T _j = 25°C | - | 150 | - | mA |
| t gt | Turn On Time | T _j = 25°C | - | 3 | - | μs |
| dv/dt | Critical Rate of Rise of Off-state Voltage, Min | T _j = 125°C, V _D = 2/3V _{DRM} Linear Voltage Rise | 1000 | | V/µs | |
| V _{T0} | Threshold Voltage, for power loss calculation only | T _j = 125°C | 0.86 | | V | |
| ľΤ | Slope Resistance, for power loss calculation only | T _j = 125°C | 1.3 | | mΩ | |

Performance Curves

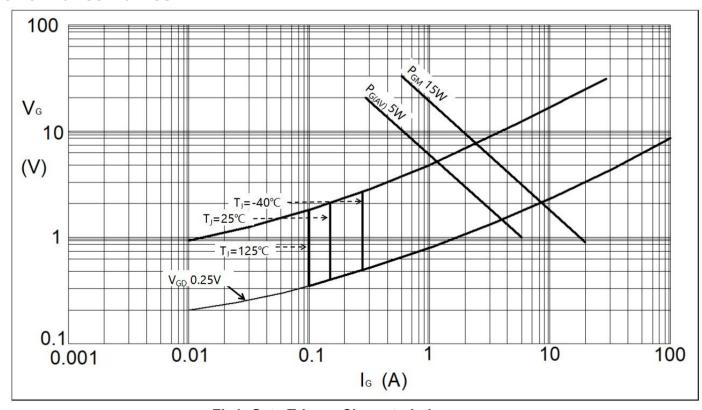


Fig1. Gate Trigger Characteristics



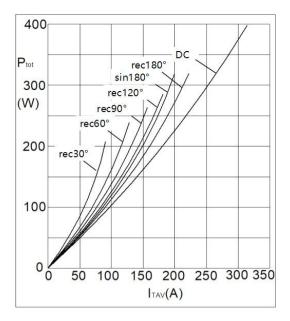


Fig2. Power Dissipation

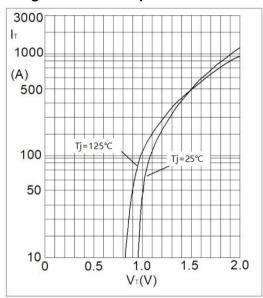


Fig4. Forward Characteristics

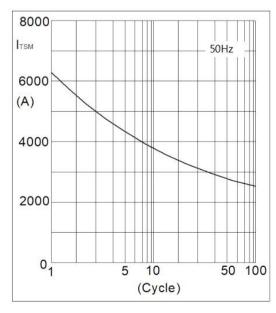


Fig6. Max Non-Repetitive Forward Surge Current

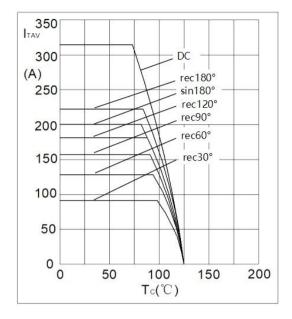


Fig3. Forward Current Derating Curve

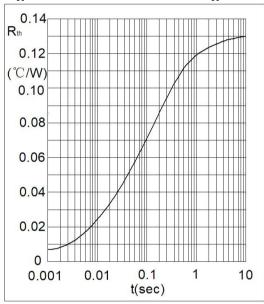
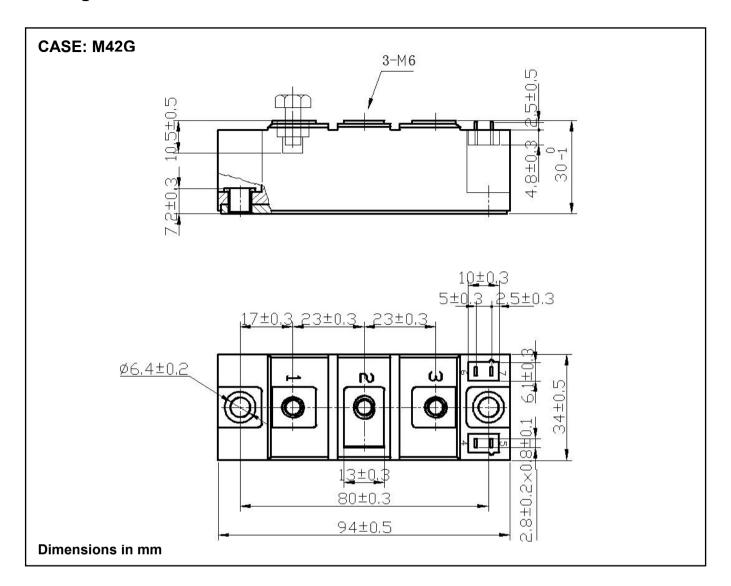


Fig5. Transient Thermal impedance



Package Outline Information



Revised: 2024-04, Revision2.1



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